



APPLICATION DATA SHEET

Electronic Version v14

Stylesheet Version v14.0

Title of Invention	METHOD OF FORMING STRAINED SILICON ON INSULATOR		
Application Type : regular, utility			
Attorney Docket Number : YOR920000707US2			
Correspondence address:			
Customer Number:		27127	
Inventor Information:			
<u>Inventor 1:</u>			
Applicant Authority Type:		Inventor	
Citizenship:		US	
Name prefix:		Mr.	
Given Name:		Kern	
Family Name:		Rim	
Residence:			
City of Residence:		Yorktown Heights	
State of Residence:		NY	
Country of Residence:		US	
Address-1 of Mailing Address:		2095 Van Cortlandt Circle	
Address-2 of Mailing Address:			
City of Mailing Address:		Yorktown Heights	
State of Mailing Address:		NY	
Postal Code of Mailing Address:		10598	
Country of Mailing Address:		US	
Phone:			
Fax:			
E-mail:			
Attorney Information:			
practitioner(s) at Customer Number:			
27127			
as my attorney(s) or agent(s) to prosecute the application identified above, and to transact all business in the United States Patent and Trademark Office connected therewith.			

Assignee 1:

Organization Name:	International Business Machines
Address-1 of Mailing Address:	Old Orchard Road
Address-2 of Mailing Address:	
City of Mailing Address:	Armonk
State of Mailing Address:	NY
Postal Code of Mailing Address:	10504
Country of Mailing Address:	US
Phone:	
Fax:	
E-mail:	